NSN 5961-01-193-5329

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-193-5329 **Inclosure Material:** Metal **Overall Length:** 1.452 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.687 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.00 reverse voltage, dc **Current Rating Per Characteristic:** 50.00 amperes source cutoff current preset and 15.00 amperes source cutoff current **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: